BL GALAXY ELECTRICAL

KBJ25A --- KBJ25M

SILICON BRIDGE RECTIFIERS

VOLTAGE RANGE: 50 --- 1000 V
CURRENT: 25.0 A

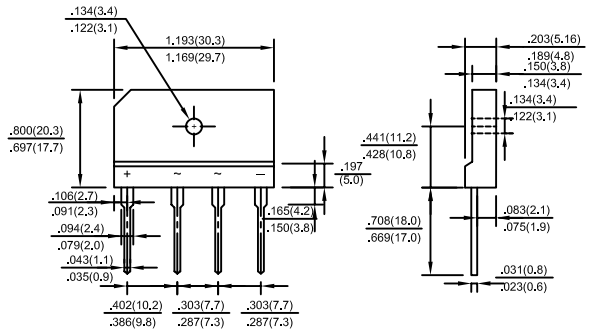
FEATURES

- ◇ Rating to 1000V PRV
- ◇ Surge overload rating to 200 Amperes peak
- ◇ Ideal for printed circuit board
- ◇ Reliable low cost construction utilizing molded plastic technique results in inexpensive product
- ◇ Lead solderable per MIL-STD-202 method 208

MECHANCAL DATA

- ◇ Polarity:Symbols molded on body
- ◇ Weight:0.23 ounces, 6.6 grams
- ◇ Mounting position: Any

KBJ



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25℃ ambient temperature unless otherwise specified.

Single phase,half wave,60 Hz,resistive or inductive load. For capacitive load,derate by 20%.

		KBJ 25A	KBJ 25B	KBJ 25D	KBJ 25G	KBJ 25J	KBJ 25K	KBJ 25M	UNITS
Maximum recurrent peak reverse voltage	V_{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS voltage	V_{RMS}	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	V_{DC}	50	100	200	400	600	800	1000	V
Maximum average forw ard Output current @T_A=25℃	$I_{F(AV)}$	25.0							A
Peak forw ard surge current 8.3ms single half-sine-w ave superimposed on rated load	I_{FSM}	200.0							A
Maximum instantaneous forw ard voltage at 12.5 A	V_F	1.0							V
Maximum reverse current @T_A=25℃	I_R	10.0							μA
at rated DC blocking voltage @T_A=100℃		1.0							mA
Typical junction capacitance per element	C_J	85							pF
Typical thermal resistance	$R_{\theta JC}$	0.6							℃/W
Operating junction temperature range	T_J	- 55 ---- + 150							℃
Storage temperature range	T_{STG}	- 55 ---- + 150							℃

NOTES:1.Measured at 1.0MH_Z and applied reverse voltage of 4.0V DC

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2.Device mounted on 300mm X 300mm X 1.6mm cu Plate heatsink.

FIG.1 -- PEAK FORWARD SURGE CURRENT

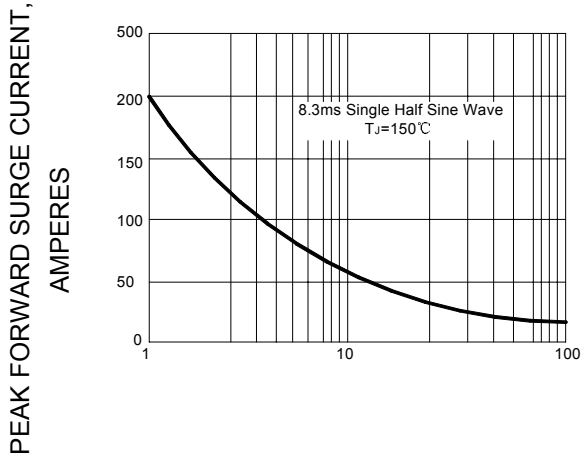


FIG.2 -- FORWARD DERATING CURVE

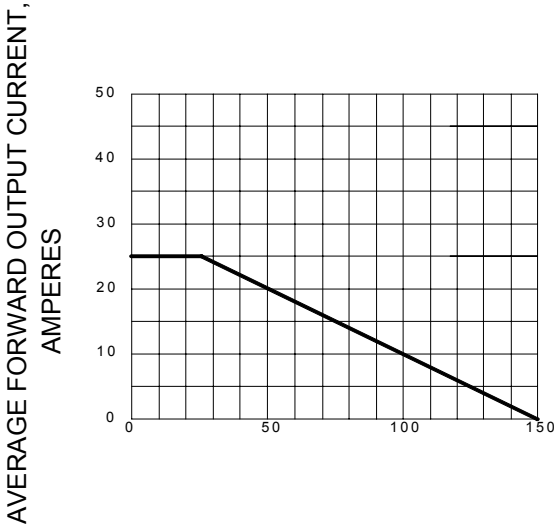


FIG.3 -- TYPICAL FORWARD CHARACTERISTIC

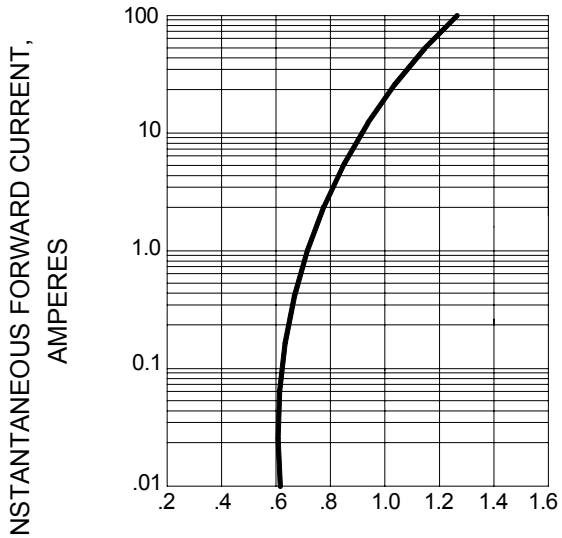


FIG.4 -- TYPICAL JUNCTION CAPACITANCE

